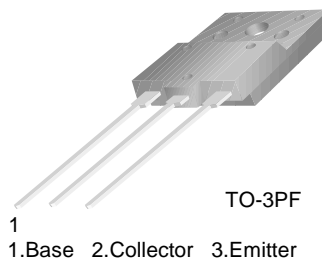


# FJAF6916

FJAF6916

## High Voltage Color Display Horizontal Deflection Output

- High Collector-Base Breakdown Voltage :  $V_{CB0} = 1700V$
- Low Saturation Voltage :  $V_{CE(sat)} = 3V$  (Max.)
- For Color Monitor



## NPN Triple Diffused Planar Silicon Transistor

### Absolute Maximum Ratings $T_C=25^\circ C$ unless otherwise noted

Symbol	Parameter	Rating	Units
$V_{CBO}$	Collector-Base Voltage	1700	V
$V_{CEO}$	Collector-Emitter Voltage	800	V
$V_{EBO}$	Emitter-Base Voltage	6	V
$I_C$	Collector Current (DC)	16	A
$I_{CP}^*$	Collector Current (Pulse)	30	A
$P_C$	Collector Dissipation	60	W
$T_J$	Junction Temperature	150	$^\circ C$
$T_{STG}$	Storage Temperature	-55 ~ 150	$^\circ C$

\* Pulse Test: PW=300 $\mu s$ , duty Cycle=2% Pulsed

### Electrical Characteristics $T_C=25^\circ C$ unless otherwise noted

Symbol	Parameter	Test Conditions	Min	Typ	Max	Units
$I_{CES}$	Collector Cut-off Current	$V_{CB}=1400V, R_{BE}=0$			1	mA
$I_{CBO}$	Collector Cut-off Current	$V_{CB}=800V, I_E=0$			10	$\mu A$
$I_{EBO}$	Emitter Cut-off Current	$V_{EB}=4V, I_C=0$			1	mA
$V_{CBO}$	Collector-Base Breakdown Voltage	$I_C=500\mu A, I_E=0$	1700			V
$V_{CEO}$	Collector-Emitter Breakdown Voltage	$I_C=5mA, I_B=0$	800			V
$V_{EBO}$	Emitter-Base Breakdown Voltage	$I_E=500\mu A, I_C=0$	6			V
$h_{FE1}$ $h_{FE2}$	DC Current Gain	$V_{CE}=5V, I_C=1A$ $V_{CE}=5V, I_C=8.5A$	10 6		9	
$V_{CE(sat)}$	Collector-Emitter Saturation Voltage	$I_C=10A, I_B=2.5A$			3	V
$V_{BE(sat)}$	Base-Emitter Saturation Voltage	$I_C=10A, I_B=2.5A$			1.5	V
$t_{STG}^*$	Storage Time	$V_{CC}=200V, I_C=8A, R_L=25\Omega$			4	$\mu s$
$t_F^*$	Fall Time	$I_{B1}=1.6A, I_{B2}=-3.2A$			0.3	$\mu s$

\* Pulse Test: PW=20 $\mu s$ , duty Cycle=1% Pulsed

### Thermal Characteristics $T_C=25^\circ C$ unless otherwise noted

Symbol	Parameter	Typ	Max	Units
$R_{\theta JC}$	Thermal Resistance, Junction to Case		2.08	$^\circ C/W$

# Typical Characteristics

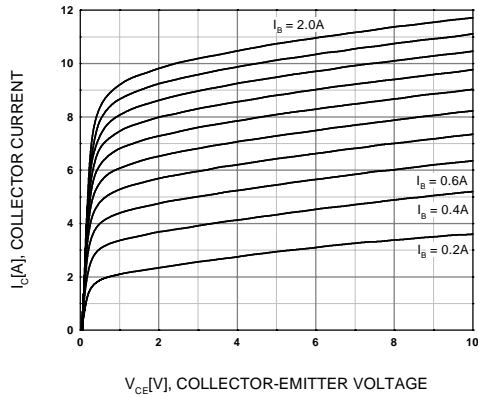


Figure 1. Static Characteristics

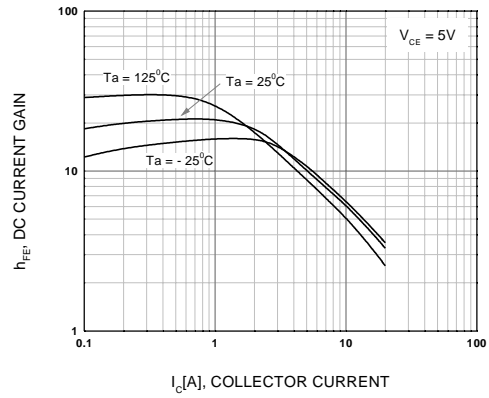


Figure 2. DC Current Gain

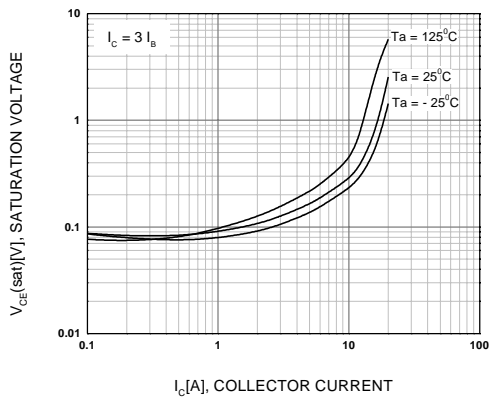


Figure 3. Collector-Emitter Saturation Voltage

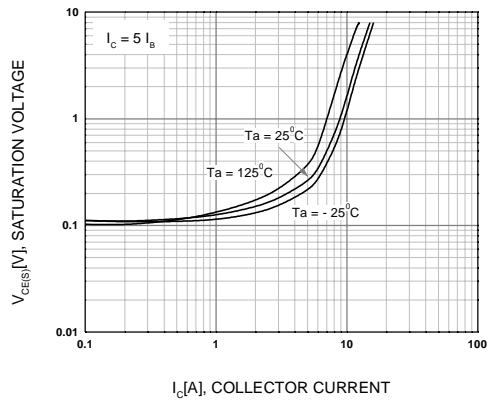


Figure 4. Collector-Emitter Saturation Voltage

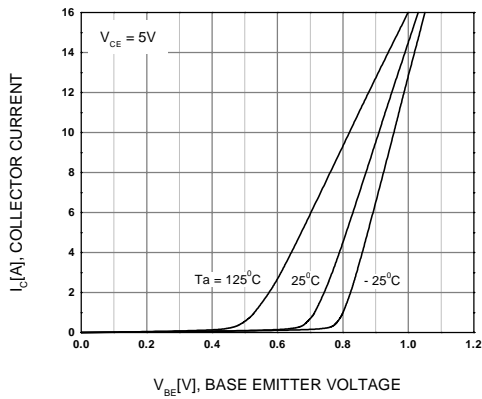


Figure 5. Base-Emitter On Voltage

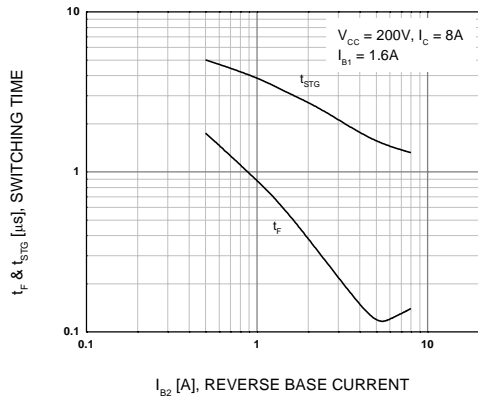


Figure 6. Resistive Load Switching Time

Typical Characteristics (Continued)

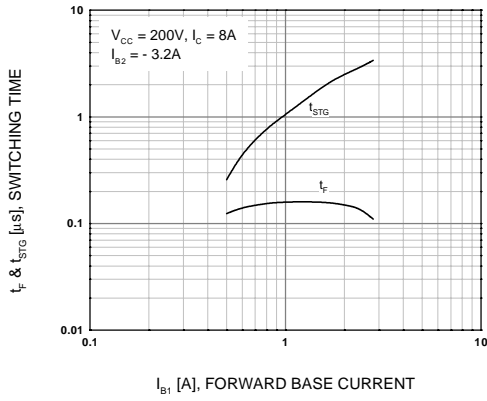


Figure 7. Resistive Load Switching Time

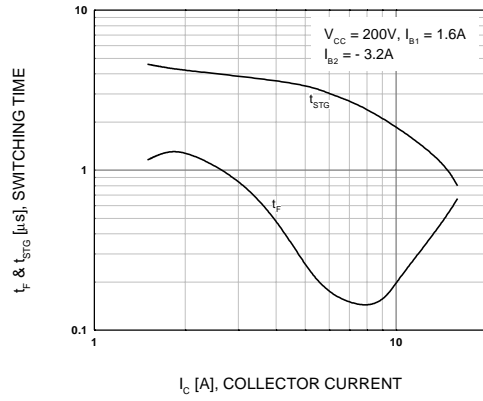


Figure 8. Resistive Load Switching Time

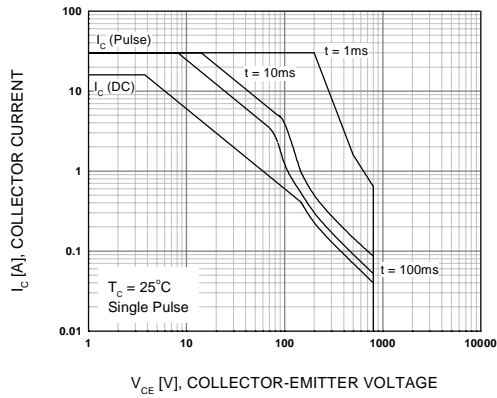


Figure 9. Forward Bias Safe Operating Area

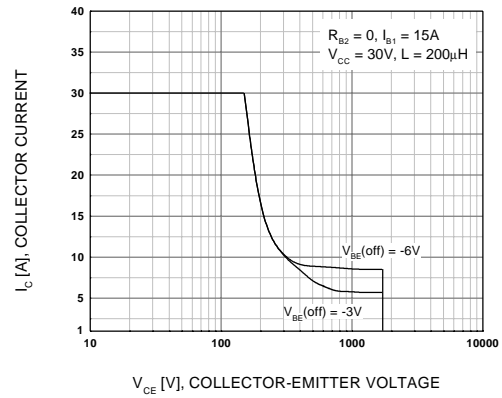


Figure 10. Reverse Bias Safe Operating Area

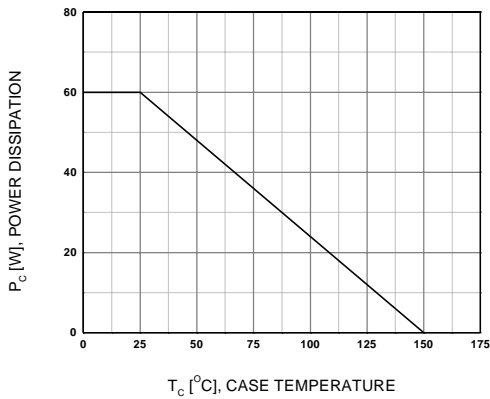


Figure 11. Power Derating



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